RoHS

COMPLIANT

HFA120FA120P

Vishay High Power Products

HEXFRED[®] Ultrafast Soft Recovery Diode, 120 A



- Fast recovery time characteristic
- · Electrically isolated base plate
- Large creepage distance between terminal
- Simplified mechanical designs, rapid assembly
- UL pending
- Totally lead (Pb)-free
- Designed and qualified for industrial level

DESCRIPTION/APPLICATIONS

The dual diode series configuration (HFA120FA120P) is used for output rectification or freewheeling/clamping operation and high voltage application.

The semiconductor in the SOT-227 package is isolated from the copper base plate, allowing for common heatsinks and compact assemblies to be built.

These modules are intended for general applications such as HV power supplies, electronic welders, motor control and inverters.

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
Cathode to anode voltage	V _R		1200	V
Continuous forward current	١ _F	T _C = 62 °C	60	
Single pulse forward current	I _{FSM}	T _J = 25 °C	350	А
Maximum repetitive forward current	I _{FRM}	Rated V_{R_i} square wave, 20 kHz, T_C = 60 °C	130	
Movimum power dissinction	D _	T _C = 25 °C	337	10/
Maximum power dissipation	FD	T _C = 100 °C	135	vv
RMS isolation voltage	VISOL	Any terminal to case, t = 1 minute	2500	V
Operating junction and storage temperature range	T _J , T _{Stg}		- 55 to + 150	°C

ELECTRICAL SPECIFICATIONS ($T_J = 25 \ ^{\circ}C$ unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V _{BR}	I _R = 100 μA	1200	-	-	
Forward voltage V _{FM}		I _F = 60 A	-	2.8	4.0	V
	V_{FM}	I _F = 120 A	-	3.6	5.3	
		$I_F = 60 \text{ A}, \text{ T}_J = 125 ^\circ\text{C}$	-	2.7	-	
		$V_{R} = V_{R}$ rated	-	2.0	75	μA
neverse leakage current IRM	$T_J = 150 \ ^{\circ}C, V_R = V_R \text{ rated}$	-	2.7	10	mA	



PRODUCT SUMMARY					
V _R	1200 V				
V _F (typical)	2.8 V				
t _{rr} (typical)	145 ns				
I _{F(DC)} at T _C	60 A at 62 °C				

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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Poverse recovery time	+	T _J = 25 °C		-	145	-	20
Reverse recovery time t _{rr}	۲r	T _J = 125 °C	I _F = 50 A dI _F /dt = - 200 A/μs V _R = 200 V	-	218	-	115
Peak recovery current I _{RRM}		T _J = 25 °C		-	13	-	A
	IRRM	T _J = 125 °C		-	18	-	
Reverse recovery charge	0	T _J = 25 °C		-	910	-	nC
	Q _{rr}	T _J = 125 °C		-	1920	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Junction to case, single leg conducting	Б		-	-	0.37	
Junction to case, both legs conducting	h thJC		-	-	0.185	°C/W
Case to heatsink	R _{thCS}	Flat, greased and surface	-	0.05	-	
Weight			-	30	-	g
Mounting torque			-	1.3	-	Nm





Fig. 3 - Maximum Thermal Impedance Z_{thJC} Characteristics



Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current



Fig. 5 - Forward Power Loss Characteristics

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Fig. 6 - Typical Reverse Recovery Time vs. dl_F/dt







Fig. 8 - Typical Peak Recovery Current vs. dl_F/dt

Note

- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$; Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 5); $Pd_{REV} =$ Inverse power loss = $V_{R1} \times I_R (1 D)$; I_R at $V_{R1} =$ Rated V_R



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Fig. 9 - Reverse Recovery Parameter Test Circuit



Fig. 10 - Reverse Recovery Waveform and Definitions

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HEXFRED[®] Ultrafast Soft Recovery Diode, 120 A

ORDERING INFORMATION TABLE

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LINKS TO RELATED DOCUMENTS				
Dimensions	http://www.vishay.com/doc?95036			
Packaging information	http://www.vishay.com/doc?95037			



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